

SANYO Semiconductors DATA SHEET

MCH6653-

P-Channel Silicon MOSFET

53 — General-Purpose Switching Device Applications

Features

- 1.5V drive.
- · Composite type with 2 MOSFETs contained in a single package, facilitating high-density mounting.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-60	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	ID		-100	mA
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	-400	mA
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm ² X0.8mm) 1unit	0.6	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	UIIIL
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-60			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-60V, V _{GS} =0V			-1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±8V, VDS=0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =-10V, I _D =-100μA	-0.4		-1.4	V
Forward Transfer Admittance	yfs	V _{DS} =-10V, I _D =-50mA	130	220		mS
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=-50mA, VGS=-4V		6.5	8.5	Ω
	R _{DS} (on)2	I _D =-30mA, V _G S=-2.5V		7.4	11	Ω
	R _{DS} (on)3	ID=-10mA, VGS=-1.5V		10	20	Ω

Marking: XE Continued on next page.

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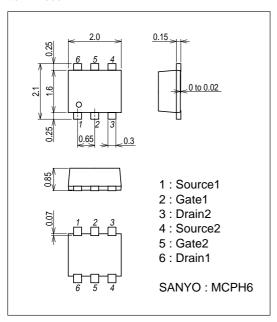
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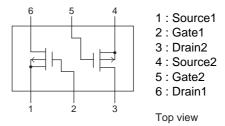
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Input Capacitance	Ciss	V _{DS} =-20V, f=1MHz		15		pF
Output Capacitance	Coss	V _{DS} =-20V, f=1MHz		3.5		pF
Reverse Transfer Capacitance	Crss	V _{DS} =-20V, f=1MHz		1.0		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		75		ns
Rise Time	t _r	See specified Test Circuit.		116		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		665		ns
Fall Time	tf	See specified Test Circuit.		270		ns
Total Gate Charge	Qg	V _{DS} =-30V, V _{GS} =-4V, I _D =-100mA		0.58		nC
Gate-to-Source Charge	Qgs	V _{DS} =-30V, V _{GS} =-4V, I _D =-100mA		0.14		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =-30V, V _{GS} =-4V, I _D =-100mA		0.03		nC
Diode Forward Voltage	V _{SD}	I _S =-100mA, V _{GS} =0V		-0.91	-1.5	V

Package Dimensions

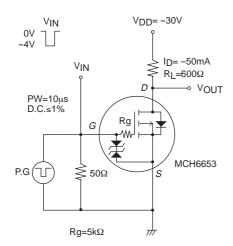
unit : mm (typ) 7022A-006

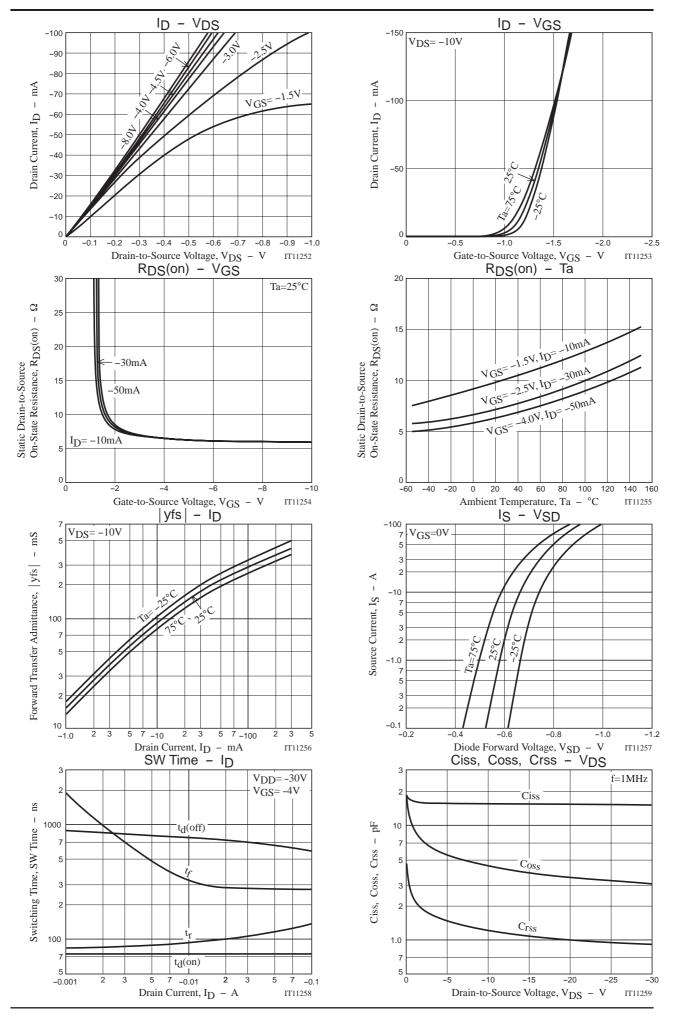


Electrical Connection

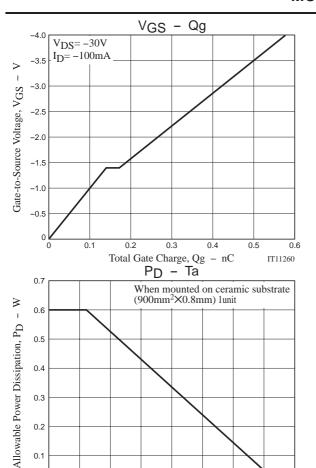


Switching Time Test Circuit





MCH6653



0

20

40

60

80

Ambient Temperature, Ta - °C

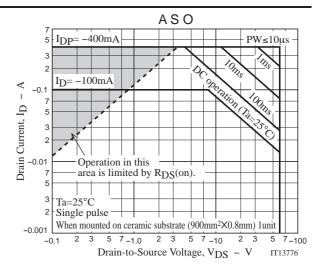
100

120

140

160

IT13777



Note on usage: Since the MCH6653 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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